

CRYSTAL OSCILLATOR SPXO

SG-615 series SG-531/SG-51 series

- Frequency range : 1.025 MHz to 135 MHz
- Supply voltage : 3.3 V / 5.0 V
- Function : Output enable(OE) Standby($\overline{ST}$)
- Pin compatible with full-size metal can. (SG-51 series)
- Pin compatible with half-size metal can. (SG-531 series)



Actual size

SG-615



SG-531



SG-51



Specifications (characteristics)

Item	Symbol	Specifications			Remarks
		SG-615P SG-531P SG-51P	SG-615PTJ SG-531PTJ SG-51PTJ	SG-615PH SG-531PH SG-51PH	
Output frequency range	f ₀	1.025 MHz to 26 MHz	26.001 MHz to 66.667 MHz		.
Supply voltage	V _{cc}	5.0 V ±0.5 V			
Temperature range	Storage temperature T _{stg}	-55 °C to +125 °C			Store as bare product after unpacking
	Operating temperature T _{use}	-20 °C to +70 °C			
Frequency tolerance	F _{tol(osc)}	B: ±50 × 10 ⁻⁶ , C: ±100 × 10 ⁻⁶			-20 °C to +70 °C *1
Current consumption	I _{cc}	23 mA Max.	35 mA Max.		No load condition
Output disable current	I _{dis}	12 mA Max.	28 mA Max.	20 mA Max.	OE=GND
Symmetry	SYM	40 % to 60 %	—	40 % to 60 %	CMOS load:50 % V _{cc} level
		40 % to 60 %	45 % to 55 %	—	TTL load: 1.4 V level
High output voltage	V _{OH}	V _{cc} -0.4 V Min.	2.4 V Min.	V _{cc} -0.4 V Min.	I _{OH} = -400 μA(P,PTJ)/-4 mA(PH)
Low output voltage	V _{OL}	0.4 V Max.			I _{OL} =16 mA(P)/ 8 mA(PTJ)/ 4 mA(PH)
Output load condition (TTL)	L _{TTL}	10 TTL Max.	5 TTL Max.	—	L _{CMOS} ≤ 15 pF
Output load condition (CMOS)	L _{CMOS}	50 pF Max.	—	50 pF Max.	
Output enable / disable input voltage	V _{IH}	2.0 V Min.	3.5 V Min.	2.0 V Min.	I _{IH} = 1 μA Max. (OE=V _{cc})
	V _{IL}	0.8 V Max.	1.5 V Max.	0.8 V Max.	I _{IL} = -100 μA Min. (OE=GND), PTJ:I _{IL} = -500 μA Min.(OE=GND)
Output rise and fall time	t _r / t _f	8 ns Max.	—	7 ns Max.	CMOS load:20 % V _{cc} to 80 % V _{cc} level
		8 ns Max.	5 ns Max.	—	TTL load:0.4 V to 2.4 V level
Oscillation start up time	t _{osc}	4 ms Max.	10 ms Max.		Time at minimum supply voltage to be 0 s
Frequency aging	F _{aging}	±5 × 10 ⁻⁶ / year Max.			+25 °C, V _{cc} =5.0 V, First year

*1 "B" tolerance will be available up to 55 MHz.

Specifications (characteristics)

Item	Symbol	Specifications			Remarks
		SG-615PCG SG-531PCG	SG-615SCG SG-531SCG	SG-615PCN	
Output frequency range	f_0	1.500 MHz to 26.000 MHz		26.001 MHz to 66.667 MHz	
Supply voltage	V _{cc}	2.7 V to 3.6 V		3.0 V to 3.6 V	
Temperature range	Storage temperature	-55 °C to +125 °C			Store as bare product after unpacking
	Operating temperature				
	T _{stg}				
	T _{use}	-40 °C to +85 °C			
Frequency tolerance	F _{tol(osc)}	B: $\pm 50 \times 10^{-6}$ C: $\pm 100 \times 10^{-6}$ M: $\pm 100 \times 10^{-6}$			-20 °C to +70 °C -40 °C to +85 °C
Current consumption	I _{cc}	12 mA Max.		20 mA Max.	No load condition
Output disable current	I _{dis}	10 mA Max.	—	10 mA Max.	OE=GND (PCG,PCN)
Stand-by current	I _{std}	—	50 μ A Max.	—	$\overline{ST}$ =GND (SCG)
Symmetry	SYM	45 % to 55 %			50 % V _{cc} level, L _{CMOS} =Max.
High output voltage	V _{OH}	V _{cc} -0.4 V Min.		V _{cc} -0.4 V Min.	I _{OH} = -8 mA
Low output voltage	V _{OL}	0.4 V Max.		0.4 V Max.	I _{OL} = 8 mA
Output load condition	L _{CMOS}	25 pF Max.		15 pF Max.	
Output enable / disable input voltage	V _{IH}	70 % V _{cc} Min.		70 % V _{cc} Min.	OE Terminal, $\overline{ST}$ Terminal
	V _{IL}	20 % V _{cc} Max.		30 % V _{cc} Max.	
Output rise and fall time	t _r / t _f	4 ns Max.			20 % V _{cc} to 80 % V _{cc} level, L _{CMOS} $\leq$ Max.
Oscillation start up time	t _{osc}	12 ms Max.		10 ms Max.	t=0 at 90 % V _{cc}
Frequency aging	F _{aging}	$\pm 5 \times 10^{-6}$ / year Max.			+25 °C, V _{cc} =3.3 V, First year

Specifications (characteristics)

Item		Symbol	Specifications			Remarks
			SG-615PTW / STW SG-531PTW / STW	SG-615PHW / SHW SG-531PHW / SHW	SG-615PCW / SCW SG-531PCW / SCW	
Output frequency range		f ₀	55.001 MHz to 135.000 MHz		26.001 MHz to 135.000 MHz	
Supply voltage		V _{cc}	5.0 V ±0.5 V		3.3 V ±0.3 V	
Temperature range	Storage temperature	T _{stg}	-55 °C to +125 °C			Store as bare product after unpacking
	Operating temperature	T _{use}	-20 °C to +70 °C		-40 °C to +85 °C	
Frequency tolerance		F _{tol(osc)}	B: ±50 × 10 ⁻⁶ , C: ±100 × 10 ⁻⁶			-20 °C to +70 °C *1
			—			-40 °C to +85 °C
Current consumption		I _{cc}	45 mA Max.		28 mA Max.	No load condition(Max. frequency range)
Output disable current		I _{dis}	30 mA Max.		16 mA Max.	OE=GND (PTW,PHW,PCW)
Stand-by current		I _{std}	50 μA Max.			ST =GND (STW,SHW,SCW)
Symmetry		SYM	—	40 % to 60 %		50 % V _{cc} level, L _{CMOS} =Max.
			40 % to 60 %	—		1.4 V level ,L _{CMOS} =Max.
High output voltage		V _{OH}	V _{cc} -0.4 V Min.			I _{OH} = -16 mA(PTW,STW,PHW,SHW), -8 mA(PCW,SCW)
Low output voltage		V _{OL}	0.4 V Max.			I _{OL} = 16 mA(PTW,STW,PHW,SHW), 8 mA(PCW,SCW)
Output load condition (TTL)		L _{TTL}	5 TTL Max.	—	—	f ₀ ≤ 90 MHz , Max.supply voltage
Output load condition (CMOS)		L _{CMOS}	15 pF Max.			Max.frequency , Max.supply voltage
Output enable /		V _{IH}	2.0 V Min.		70 % V _{cc} Min.	OE Terminal , ST Terminal
disable input voltage		V _{IL}	0.8 V Max.		20 % V _{cc} Max.	
Output rise and fall time		t _r / t _f	—	4 ns Max.		20 % V _{cc} to 80 % V _{cc} level, L _{CMOS} ≤ Max.
			4 ns Max.	—	—	0.4 V to 2.4 V level
Oscillation start up time		t _{osc}	10 ms Max..			Time at minimum supply voltage to be 0 s
Frequency aqing		F _{aging}	±5 × 10 ⁻⁶ / year Max.			+25 °C, V _{cc} =5.0 V / 3.3 V, First year

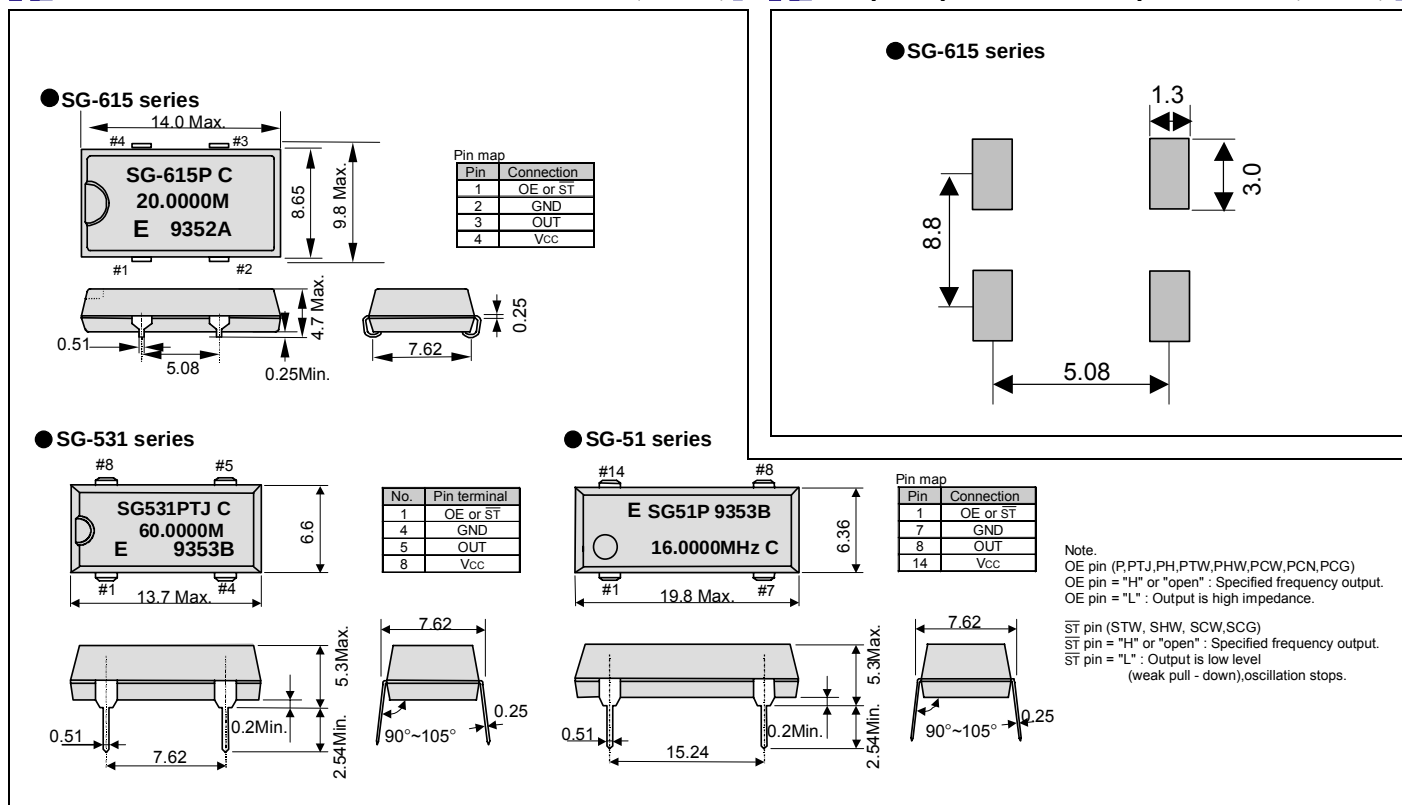
*1 "C" tolerance : $f_0 \geq 66.667$ MHz (PTW,STW,PHW,SHW)

External dimensions

(Unit:mm)

Footprint (Recommended)

(Unit:mm)



“3D STRATEGY” EPSON TOYOCOM

In order to meet customer needs in a rapidly advancing digital, broadband and ubiquitous society, we are committed to offering products that are one step ahead of the market and a rank above the rest in quality. To achieve our goals, we follow a “3D (three device) strategy” designed to drive both horizontal and vertical growth. We will to grow our three device categories of “Timing Devices”, “Sensing Devices” and “Optical Devices”, and expand vertical growth through a combination of products from these categories.

Quartz devices have become crucial in the network environment where products are increasingly intended for broadband, ubiquitous applications and where various types of terminals can transfer information almost immediately via LAN and WAN on a global scale. Epson Toyocom Corporation addresses every single aspect within a network environment. The new corporation offers “Digital Convergence” solutions to problems arising with products for consumer use, such as, core network systems and automotive systems.

PROMOTION OF ENVIRONMENTAL MANAGEMENT SYSTEM CONFORMING TO INTERNATIONAL STANDARDS

At Epson Toyocom, all environmental initiatives operate under the Plan-Do-Check-Action(PDCA) cycle designed to achieve continuous improvements. The environmental management system (EMS) operates under the ISO 14001 environmental management standard. All of our major manufacturing and non-manufacturing sites, in Japan and overseas, completed the acquisition of ISO 14001 certification. In the future, new group companies will be expected to acquire the certification around the third year of operations.

ISO 14000 is an international standard for environmental management that was established by the International Standards Organization in 1996 against the background of growing concern regarding global warming, destruction of the ozone layer, and global deforestation.

WORKING FOR HIGH QUALITY

Epson Toyocom quickly began working to acquire company-wide ISO 9000 series certification, and has acquired ISO 9001 or ISO 9002 certification for all targeted products manufactured in Japanese and overseas plants.

Epson Toyocom has acquired QS-9000 certification, which is of a higher level. Also, TS 16949 certification, which is also of a higher level, has been acquired.

QS-9000 is an enhanced standard for quality assurance systems formulated by leading U.S.automobile manufacturers based on the international ISO 9000 series.

ISO/TS 16949 is a global standard based on QS-9000, a severe standard corresponding to the requirements from the automobile industry.

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